Iwona Jozwik

List of Publications by Year in descending order

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		687363	580821
54	683	13	25
papers	citations	h-index	g-index
55	55	55	989
all docs	docs citations	times ranked	citing authors

#	Article	IF	CITATIONS
1	Direct visualization of highly resistive areas in GaN by means of low-voltage scanning electron microscopy. Materials Science in Semiconductor Processing, 2022, 138, 106293.	4.0	2
2	Formation of GeO2 under Graphene on Ge(001)/Si(001) Substrates Using Water Vapor. Molecules, 2022, 27, 3636.	3.8	O
3	MOCVD growth of gallium and indium microparticles for SERS applications. Journal of Materials Science: Materials in Electronics, 2021, 32, 8958-8964.	2.2	2
4	Bulk nanocomposite made of ZnO lamellae embedded in the ZnWO4 matrix: growth from the melt. Journal of Materials Science, 2021, 56, 11219-11228.	3.7	6
5	Resistivity contrast imaging in semiconductor structures using ultra-low energy scanning electron microscopy. Ultramicroscopy, 2021, 228, 113333.	1.9	5
6	Absolute radiation tolerance of amorphous alumina coatings at room temperature. Ceramics International, 2021, 47, 34740-34750.	4.8	12
7	Enhanced Raman spectra of hydrogen-intercalated quasi-free-standing monolayer graphene on 4H-SiC(0001). Physica E: Low-Dimensional Systems and Nanostructures, 2020, 117, 113746.	2.7	5
8	Structural and mechanical properties of different types of graphite used in nuclear applications. Journal of Molecular Structure, 2020, 1217, 128370.	3 . 6	4
9	Influence of ion irradiation on the nanomechanical properties of thin alumina coatings deposited on 316L SS by PLD. Surface and Coatings Technology, 2020, 386, 125491.	4.8	11
10	3D Depth Profile Reconstruction of Segregated Impurities using Secondary Ion Mass Spectrometry. Journal of Visualized Experiments, 2020, , .	0.3	0
11	Nanomechanical properties of low-energy Fe-ion implanted Eurofer97 and pure Fe. Surface and Coatings Technology, 2020, 393, 125833.	4.8	5
12	Study of the electrical properties of ion irradiated polymer materials. Surface and Coatings Technology, 2020, 388, 125562.	4.8	13
13	Highly Conductive Doped Hybrid Carbon Nanotube–Graphene Wires. ACS Applied Materials & Interfaces, 2019, 11, 33207-33220.	8.0	22
14	Ion-Irradiated Damage in Semiconductors Visualized by Means of Low-kV Scanning Electron Microscopy. Microscopy and Microanalysis, 2019, 25, 486-487.	0.4	1
15	Ni(111) Thin Layers Recrystallization Studied by SEM, EBSD and AFM. Microscopy and Microanalysis, 2019, 25, 1982-1983.	0.4	O
16	Damage-induced voltage alteration (DIVA) contrast in SEM images of ion-irradiated semiconductors. Ultramicroscopy, 2019, 204, 6-9.	1.9	3
17	High resolution SEM characterization of nanoâ€precipitates in ODS steels. Microscopy Research and Technique, 2018, 81, 502-508.	2.2	5
18	Evaluation of consolidation method on mechanical and structural properties of ODS RAF steel. Applied Surface Science, 2018, 446, 215-221.	6.1	12

#	Article	IF	Citations
19	Mechanical and structural properties of ODS RAF steels submitted to low-energy ions irradiation. Fusion Engineering and Design, 2018, 127, 54-59.	1.9	23
20	Functional properties of poly(tetrafluoroethylene) (PTFE) gasket working in nuclear reactor conditions. Journal of Molecular Structure, 2018, 1157, 306-311.	3.6	19
21	Ion-irradiated butadiene acrylonitrile rubber reinforced with graphene filler. Nuclear Instruments & Methods in Physics Research B, 2018, 435, 323-326.	1.4	6
22	Influence of consolidation process on functional properties of steels. Surface and Coatings Technology, 2018, 355, 234-239.	4.8	7
23	Damage accumulation studies in ion-irradiated oxides: Current status and new perspectives. Nuclear Instruments & Methods in Physics Research B, 2018, 435, 2-7.	1.4	6
24	Low energy cathodoluminescence analysis of damage build-up in ion irradiated spinel mono- and polycrystals. Nuclear Instruments & Methods in Physics Research B, 2018, 435, 290-295.	1.4	1
25	Thermally activated double-carrier transport in epitaxial graphene on vanadium-compensated 6H-SiC as revealed by Hall effect measurements. Carbon, 2018, 139, 776-781.	10.3	16
26	Carbon nanotube fibers doped with iron via Fenton reaction. , 2018, , .		0
27	CNT fibers p-doped with F4TCNQ (2,3,5,6-Tetrafluoro-7,7,8,8-tetracyanoquinodimethane)., 2017,,.		1
28	The effect of Ar-ion irradiation on nanomechanical and structural properties of ODS RAF steels manufactured by using HIP technique. Vacuum, 2017, 145, 144-152.	3.5	12
29	Identification of the Zirconia Phases by Means of Raman Spectroscopy for Specimens Prepared by FIB Lift-Out Technique. Oxidation of Metals, 2017, 88, 521-530.	2.1	9
30	Communicationâ€"Direct Imaging of Irradiation Damage in Semiconductors by Low-Energy SEM. ECS Journal of Solid State Science and Technology, 2017, 6, P415-P417.	1.8	5
31	Graphene growth on Ge(100)/Si(100) substrates by CVD method. Scientific Reports, 2016, 6, 21773.	3.3	83
32	Low-noise epitaxial graphene on SiC Hall effect element for commercial applications. Applied Physics Letters, 2016, 108, .	3.3	21
33	Structural and functional properties of ion-irradiated graphene-reinforced elastomers. Surface and Coatings Technology, 2016, 306, 176-180.	4.8	7
34	Comparative study of radiation-induced damage in magnesium aluminate spinel by means of IL, CL and RBS/C techniques. Physics and Chemistry of Minerals, 2016, 43, 439-445.	0.8	12
35	Study of sub-oxide phases at the metal-oxide interface in oxidized pure zirconium and Zr-1.0% Nb alloy by using SEM/FIB/EBSD and EDS techniques. Journal of Nuclear Materials, 2016, 476, 56-62.	2.7	43
36	Conductivity Contrast in SEM Images of Hydrogenated Graphene Grown on SiC. Microscopy and Microanalysis, 2015, 21, 31-32.	0.4	1

#	Article	lF	Citations
37	Analysis of Radiation Damage in Magnesium Aluminate Spinel by Means of Cathodoluminescence. Microscopy and Microanalysis, 2015, 21, 1005-1006.	0.4	0
38	When Eutectics Meet Plasmonics: Nanoplasmonic, Volumetric, Selfâ€Organized, Silverâ€Based Eutectic. Advanced Optical Materials, 2015, 3, 381-389.	7.3	38
39	Formation mechanism of graphene buffer layer on SiC(0 0 0 1). Carbon, 2015, 81, 63-72.	10.3	33
40	Ion beam-induced luminescence as method of characterization of radiation damage in polycrystalline materials. Nuclear Instruments & Methods in Physics Research B, 2015, 365, 273-277.	1.4	4
41	Low-kV SEM Imaging of Epitaxial Graphene Grown on Various Substrates. Microscopy and Microanalysis, 2014, 20, 18-19.	0.4	2
42	Irradiated rareâ€earthâ€doped powellite single crystal probed by confocal Raman mapping and transmission electron microscopy. Journal of Raman Spectroscopy, 2014, 45, 383-391.	2.5	15
43	The influence of pressure on growth of 3C-SiC heteroepitaxial layers on silicon substrates. Journal of Crystal Growth, 2014, 401, 542-546.	1.5	2
44	Structural stability of Nd2Zr2O7 pyrochlore ion-irradiated in a broad energy range. Acta Materialia, 2013, 61, 6492-6505.	7.9	55
45	Effect of combined local variations in elastic and inelastic energy losses on the morphology of tracks in ion-irradiated materials. Acta Materialia, 2013, 61, 4669-4675.	7.9	19
46	RBS/C, HRTEM and HRXRD study of damage accumulation in irradiated SrTiO3. Radiation Effects and Defects in Solids, 2013, 168, 442-449.	1.2	3
47	HRTEM study of track evolution in 120-MeV U irradiated Gd2Ti2O7. Nuclear Instruments & Methods in Physics Research B, 2012, 286, 258-261.	1.4	12
48	Hydrogen loss from elastomers subjected to ion irradiation. Materials Chemistry and Physics, 2011, 127, 342-346.	4.0	9
49	Phase transformations induced by high electronic excitation in ion-irradiated Gd2(ZrxTi1â^'x)2O7 pyrochlores. Journal of Applied Physics, 2010, 108, .	2.5	93
50	Influence of LPE process technological conditions on Si ELO layers morphology. Journal of Non-Crystalline Solids, 2008, 354, 4287-4289.	3.1	1
51	Analysis of ambient gas influence on silicon layers crystallized by means of LPE. Journal of Non-Crystalline Solids, 2008, 354, 4423-4425.	3.1	2
52	Interdigitated back contact solar cells with SiO2 and SiN back surface passivation. Journal of Non-Crystalline Solids, 2008, 354, 4341-4344.	3.1	5
53	Two-Step Liquid Phase Epitaxy Growth of Silicon on Patterned Silicon Substrates in Ar Atmosphere. , 2006, , .		1
54	The epitaxial lateral overgrowth of silicon by two-step liquid phase epitaxy. Journal of Crystal Growth, 2006, 294, 367-372.	1.5	9